	<h2>SI3442CDV-T1-GE3</h2>
	<p>Hersteller-Teilenummer: SI3442CDV-T1-GE3</p> <p>Hersteller / Marke: Electro-Films (EFI) / Vishay</p> <p>Teil der Beschreibung: MOSFET N-CH 20V 8A 6TSOP</p> <p>Datenblätter:  SI3442CDV-T1-GE3.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 9630 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	SI3442CDV-T1-GE3
Hersteller	Electro-Films (EFI) / Vishay
Beschreibung	MOSFET N-CH 20V 8A 6TSOP
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs ,
Teilstatus	9630 pcs Stock
detaillierte Beschreibung	N-Channel 20V 8A (Tc) 1.7W (Ta), 2.7W (Tc) Surface
Serie	TrenchFET®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	SOT-23-6 Thin, TSOT-23-6
Supplier Device-Gehäuse	6-TSOP
Verlustleistung (max)	1.7W (Ta), 2.7W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	20V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	8A (Tc)
Rds On (Max) @ Id, Vgs	27 mOhm @ 6.5A, 10V
VGS (th) (Max) @ Id	1.5V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	14nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	335pF @ 10V
Antriebsspannung (Max Rds On, Min Rds On)	2.5V, 10V
Vgs (Max)	±12V
Verpackung	Tape & Reel (TR)
Bleifreier Status / RoHS-Status	Lead free / RoHS Compliant
Feuchtigkeitsempfindlichkeitsniveau (MSL)	1 (Unlimited)
Andere Namen	SI3442CDV-T1-GE3TR















































SI3442CDV-T1-GE3 ist neu im Original. Suche SI3442CDV-T1-GE3 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie SI3442CDV-T1-GE3 Electro-Films (EFI) / Vishay mit Garantie und Vertrauen. Anfrage SI3442CDV-T1-GE3: Info@Y-IC.com

Sie können auch interessiert sein:

 SI3442DDV-T1-E3 VISHAY VISHAY SOT-163	 SI3442CDV-T1-GE3 Vishay / Siliconix MOSFET N-CH 20V 8A 6TSOP	 SI3442CDV-T1-E3 Son Son TSOP-6	 SI3442CDV V V TSOP-6
 SI3442BDV-T1-GE3 Electro-Films (EFI) / Vishay MOSFET N-CH 20V 3A 6-TSOP	 SI3442DV AMI Semiconductor / ON Semiconductor MOSFET N-CH 20V 4.1A SSOT-6	 SI3442DV-T1 VISHAY SI3442DV-T1 VISHAY	 SI3442DV T1 42NE SI SI SOT-163

heiße Teile

Mehr

 SI3438DV-T1-GE3	 SI3438DV-T1-GE3	 SI3440ADV-T1-GE3	 SI3440ADV-T1-GE3	 SI3440DV-T1-E3
 SI3440DV-T1-E3	 SI3440DV-T1-E3	 SI3440DV-T1-E3	 SI3441BDV	 SI3441BDV-T1
 SI3441BDV-T1-E3	 SI3441BDV-T1-E3	 SI3441BDV-T1-E3	 SI3441BDV-T1-GE3	 SI3441DV
 SI3441DV-NL	 SI3441DV-T1	 SI3441DV-T1-E3	 SI3441DV-T2	 SI3441DV-TI-E3
 SI3442BDV	 SI3442BDV-T1-E3	 SI3442BDV-T1-E3	 SI3442BDV-T1-GE3	 SI3442BDV-T1-GE3
 SI3442CDV-T1-GE3	 SI3442DV	 SI3442DV	 SI3442DV-T1	 SI3442DV-T1-E3
 SI3442DV-T1-GE3	 SI3443ADV-T1-E3	 SI3443BDV	 SI3443BDV-T1-E3	 SI3443BDV-T1-E3
 SI3443BDV-T1-GE3	 SI3443BDV-T1-GE3	 SI3443BVD	 SI3443CDV-T1-E3	 SI3443CDV-T1-E3
 SI3443CDV-T1-GE3	 SI3443CDV-T1-GE3	 SI3443DDV-T1-GE3	 SI3443DDV-T1-GE3	 SI3443DV
 SI3443DV	 SI3443DV	 SI3443DV-NL	 SI3443DV-T1	 SI3443DV-T1-E3

Contact us: Info@Y-IC.com

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